NSN 5962-01-376-1641

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View Online at https://aerobasegroup.com/nsn/5962-01-376-1641

Body Length: 1.280 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 1.2 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Electrostatic sensitive and programmed and w/disable and w/clock and w/enable and high impedance and asynchronous and bidirectional and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 22 input **Case Outline Source And Designator:** D-9 mil-m-38510 **Current Rating Per Characteristic:** 16.00 milliamperes reverse current, dc **Terminal Surface Treatment:** Solder **Product Name:** And-or-logic array - pal xp priority decode **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Capitance Rating Per Characteristic:** 10.00 input picofarads and 10.00 output picofarads **Time Rating Per Chacteristic:** 25.00 nanoseconds access

Pal

Test Data Document:

Memory Device Type:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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